

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	133	character adj projection	USPAT	OR	OFF	2004/12/16 07:41
S2	21	S1 and (circuit adj pattern)	USPAT	OR	OFF	2004/12/16 10:51
S3	3	(6481004 6560768 6543044).pn.	USPAT	OR	OFF	2004/12/15 15:49
S4	5	(6495841 6204511 6316163 6020107 5994030).pn.	USPAT	OR	OFF	2004/12/15 16:00
S5	5	(6365492 6274512 6709966 6440843 6147355).pn.	USPAT	OR	OFF	2004/12/15 16:09
S6	2	(6823294 6110213).pn.	USPAT	OR	OFF	2004/12/15 16:10
S7	731	703/6,20.ccls.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:41
S8	3	S7 and (circuit adj pattern)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:42
S9	156	703/20.ccls.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:42
S10	0	S9 and (circuit adj pattern)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:43
S11	1253	703/2.ccls.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:43
S12	10	S11 and (circuit adj pattern)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:44
S13	17851	(circuit adj pattern)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:44
S14	10396	S13 and semiconductor	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:44
S15	2701	S14 and specification	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:44

S16	1240	S15 and input	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:44
S17	465	S16 and parameter\$1	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:45
S18	52	S17 and ((charged near particle near beam) or (character adj projection))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:45
S19	52	S18 and time	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:46
S20	35	S19 and cost	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 07:46
S21	9	S20 and network	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 08:02
S22	4	(6198181 6223133 6311096 6470230).pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 08:10
S23	2	(6823294 6110231).pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 08:24
S24	1	("6110213").pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2004/12/16 08:24
S26	12036	circuit adj pattern	USPAT	OR	OFF	2004/12/16 08:32
S27	21	S26 and (character near projection)	USPAT	OR	OFF	2004/12/16 08:32
S28	17	S27 and (charged near particle near beam)	USPAT	OR	OFF	2004/12/16 08:33
S29	17	S28 and (mask or aperture)	USPAT	OR	OFF	2004/12/16 08:33
S30	1	"6162581".pn.	USPAT	OR	OFF	2004/12/16 14:40
S31	212	700/105-107.ccls.	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:41
S32	184	S31 and order	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:41
S33	96	S32 and network	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:41

S34	52	S33 and specification\$1	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:41
S35	19	S34 and parameter	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:53
S36	6	S35 and semiconductor	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:56
S37	616	700/119,182.ccls.	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:56
S38	46	S37 and semiconductor	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:56
S39	39	S38 and order	US-PGPUB; USPAT	OR	OFF	2004/12/16 14:56
S41	16	S39 and (network or internet)	USPAT	OR	OFF	2004/12/16 14:57
S42	15	S41 and (specification or parameter)	USPAT	OR	OFF	2004/12/16 14:57